



75W SILICON SWITCHING TRANSISTORS

TO-220

PNP NPN 2N6040 2N6043 2N6041 2N6044 2N6042 2N6045

T0-220 Leaded Plastic Package RoHS compliant

APPLICATIONS:

Designed for general purpose amplifier and low-speed switching applications

ABSOLUTE MAXIMUM RATINGS $(T_a = 25 \, ^{\circ}C)$

		VALUE			
PARAMETER	SYMBOL	2N6040	2N6041	2N6042	UNIT
		2N6043	2N6044	2N6045	
Collector-Emitter Voltage	V_{CEO}	60	80	100	V
Collector-Base Voltage	V_{CBO}	60	80	100	V
Emitter-Base Voltage	V_{EBO}	5		V	
Collector Current-Continuous	I _C	8.0		A	
Collector Current-Peak	I _{CM}	16			
Base Current	I _B	120		mA	
Total Power Dissipation @ T _C =25°C	Ъ	75		W	
Derate above 25°C	P _D	0.6		W/°C	
Operating and Storage Junction Temperature Range	T_J , T_{STG}	-65 to +150		°C	

THERMAL RESISTANCE

Junction to Case	$R_{\theta jc}$	1.67	°C/W	l
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4.5

V

ELECTRICAL CHARACTERISTICS (Tc = 25°C unless otherwise specified) **VALUE SYMBOL PARAMETER TEST CONDITION** UNIT MIN TYP MAX OFF CHARACTERISTICS Collector-Emitter Sustaining Voltage 1 60 2N6040, 2N6043 $V_{\text{CEO}(\text{sus})}$ ٧ $I_C = 30 \text{mA}$, $I_B = 0$ 80 2N6041, 2N6044 100 2N6042, 2N6045 Collector Cutoff Current 2N6040, 2N6043 V_{CE} =30V, I_{B} =0 0.5 I_{CEO} mA V_{CE} =40V, I_{B} =0 2N6041, 2N6044 0.5 2N6042, 2N6045 V_{CE} =50V, I_{B} =0 0.5 Collector Cutoff Current V_{CB} =60V, I_E =0V 2N6040, 2N6043 0.5 mΑ I_{CBO} 2N6041, 2N6044 V_{CB} =80V, I_{E} =0 0.5 2N6042, 2N6045 V_{CB} =100V, I_E =0 0.5 **Emitter Cutoff Current** $V_{EB} = 5.0 V, I_{C} = 0$ mΑ I_{EBO} 2.0 ON CHARACTERISTICS 1 DC Current Gain I_{C} =4.0 A, V_{CF} =4.0 V 2N6040,41,43,44 1000 20000 h_{FE} 2N6042,45 I_C =3.0 A, V_{CE} =4.0V 20000 1000 All types I_{C} =8.0 A, V_{CE} =4.0V 100 Collector-Emitter Sustaining Voltage 1 I_{C} =4.0 A, I_{B} =16 mA 2.0 2N6040,41,43,44 I_C =3.0 A, I_B =12 mA $V_{\text{CE(sat)}}$ ٧ 2.0 2N6042.45 I_{C} =8.0 A, I_{B} =80 mA 4.0 All types

 $V_{BE(sat)}$

 I_C =8.0 A, I_B =80 mA

Note:

1. Pulse Test width = 300 µs , Duty Cycle < 2.0%

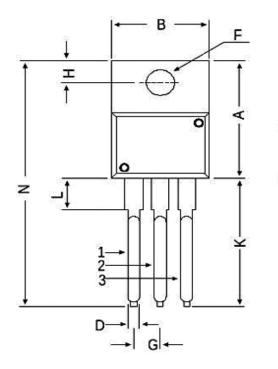
Base-Emitter Saturation Voltage

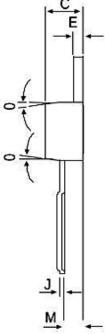




PACKAGE DETAILS

TO-220 Leaded Plastic Package



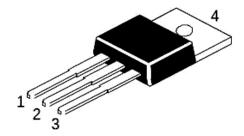


DIM	MIN	MAX
Α	14.42	16.51
В	9.63	10.67
С	3.56	4.83
D	-	0.90
Е	1.15	1.40
F	3.75	3.80
G	2.29	2.79
Н	2.54	3.43
J	-	0.56
K	12.70	14.73
L	2.80	4.07
М	2.03	2.92
N		31.24
0		7°

All Dimensions are in mm

PIN CONFIGURATION

- 1. BASE
- 2. COLLECTOR
- 3. EMITTER
- 4. COLLECTOR







Recommended Product Storage Environment for Discrete Semiconductor Devices

This storage environment assumes that the Diodes and transistors are packed properly inside the original packing supplied by CDIL.

- · Temperature 5 °C to 30 °C
- · Humidity between 40 to 70 %RH
- · Air should be clean.
- · Avoid harmful gas or dust.
- · Avoid outdoor exposure or storage in areas subject to rain or water spraying .
- · Avoid storage in areas subject to corrosive gas or dust. Product shall not be stored in areas exposed to direct sunlight.
- · Avoid rapid change of temperature.
- · Avoid condensation.
- · Mechanical stress such as vibration and impact shall be avoided.
- · The product shall not be placed directly on the floor.
- The product shall be stored on a plane area. They should not be turned upside down. They should not be placed against the wall.

Shelf Life of CDIL Products

The shelf life of products is the period from product manufacture to shipment to customers. The product can be unconditionally shipped within this period. The period is defined as 2 years.

If products are stored longer than the shelf life of 2 years the products shall be subjected to quality check as per CDIL quality procedure.

The products are further warranted for another one year after the date of shipment subject to the above conditions in CDIL original packing.

Floor Life of CDIL Products and MSL Level

When the products are opened from the original packing, the floor life will start.

For this, the following JEDEC table may be referred:

JEDEC MSL Level			
Level	Time	Condition	
1	Unlimited	≤30 °C / 85% RH	
2	1 Year	≤30 °C / 60% RH	
2a	4 Weeks	≤30 °C / 60% RH	
3	168 Hours	≤30 °C / 60% RH	
4	72 Hours	≤30 °C / 60% RH	
5	48 Hours	≤30 °C / 60% RH	
5a	24 Hours	≤30 °C / 60% RH	
6	Time on Label(TOL)	≤30 °C / 60% RH	







Customer Notes

Component Disposal Instructions

- CDIL Semiconductor Devices are RoHS compliant, customers are requested to please dispose as per prevailing Environmental Legislation of their Country.
- 2. In Europe, please dispose as per EU Directive 2002/96/EC on Waste Electrical and Electronic Equipment (WEEE).

The product information and the selection guides facilitate selection of the CDIL's Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished in the Data Sheet and on the CDIL Web Site/CD are believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s).

CDIL strives for continuous improvement and reserves the right to change the specifications of its products without prior notice.



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